







TPL5110-Q1

ZHCSG15A - FEBRUARY 2017 - REVISED SEPTEMBER 2021

# 用于电源门控的毫微级功耗系统计时器 TPL5110-Q1 AEC-Q100

## 1 特性

- 符合汽车应用要求
- 具有符合 AEC-Q100 标准的下列特性:
  - 器件温度等级 1:-40°C 至 125°C 环境工作温度 范围
  - 器件 HBM ESD 分类等级 2
  - 器件 CDM ESD 分类等级 C5
- 提供功能安全
  - 可帮助进行功能安全系统设计的文档
- 电压为 2.5V 时, 电流消耗为 35nA (典型值)
- 电源电压范围为 1.8V 至 5.5V
- 可选计时间隔: 100ms 至 7200s
- 计时器精度:1%(典型值)
- 可通过电阻选择时间间隔
- 手动为 MOSFET 上电
- 单次触发功能
- TPL5x10Q 系列 AEC-Q100 毫微级功耗系统计时
  - TPL5010-Q1:具备可编程延迟范围的看门狗功
  - TPL5110-Q1:具有可编程延迟范围和单次触发 特性的 MOS 驱动器

## 2 应用

- 电动汽车
- 电池供电型系统
- 离合器执行器电路
- 车门把手电路
- 智能钥匙
- 远程电流传感器
- 入侵者检测

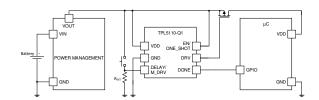
## 3 说明

TPL5110-Q1 毫微级计时器是一种集成了 MOSFET 驱 动器且通过 AEC-Q100 认证的低功耗计时器,非常适 合占空比或电池供电型应用中的电源门控。TPL5110-Q1 的电流消耗仅为 35nA,可用于支持电源线路,并 大幅降低系统睡眠期间的总待机电流。利用这一节能特 性可以明显缩小电池尺寸,使得 TPL5111 成为能量采 集或无线传感器应用的理想选择。TPL5110-Q1 可提供 100ms 至 7200s 的可选计时间隔,适用于电源门控应 用。此外, TPL5110-Q1 还具有独特的单次触发功能, 计时器可仅在一个周期内为 MOSFET 供电。 TPL5110-Q1 采用 6 引脚 SOT23 封装。

### 器件信息(1)

| 器件型号       | 封装        | 封装尺寸(标称值)       |
|------------|-----------|-----------------|
| TPL5110-Q1 | SOT23 (6) | 3.00mm x 3.00mm |

如需了解所有可用封装,请参阅数据表末尾的可订购产品附 录。



简化版应用原理图



## **Table of Contents**

| 1 特性   | 1 | 7.4 Device Functional Modes             | g                |
|--|---|---|------------------|
| . · · · <u>· · · · · · · · · · · · · · · ·</u> |   | 7.5 Programming                         | 11               |
| - <i>—,-</i><br>3 说明                           |   | 8 Application and Implementation        |                  |
| 4 Revision History                             |   | 8.1 Application Information             | 17               |
| 5 Pin Configuration and Functions              |   | 8.2 Typical Application                 | 17               |
| 6 Specifications                               |   | 9 Power Supply Recommendations          | 18               |
| 6.1 Absolute Maximum Ratings                   |   | 10 Layout                               | 19               |
| 6.2 ESD Ratings                                |   | 10.1 Layout Guidelines                  | 19               |
| 6.3 Recommended Operating Ratings              |   | 10.2 Layout Example                     | 19               |
| 6.4 Thermal Information                        |   | 11 Device and Documentation Support     | <mark>2</mark> 0 |
| 6.5 Electrical Characteristics                 |   | 11.1 接收文档更新通知                           | 20               |
| 6.6 Timing Requirements                        |   | 11.2 支持资源                               | 20               |
| 6.7 Typical Characteristics                    |   | 11.3 Trademarks                         |                  |
| 7 Detailed Description                         |   | 11.4 Electrostatic Discharge Caution    | 20               |
| 7.1 Overview                                   |   | 11.5 术语表                                |                  |
| 7.2 Functional Block Diagram                   |   | 12 Mechanical, Packaging, and Orderable |                  |
| 7.3 Feature Description                        |   | Information                             | 21               |
| •  |   |   |                  |

# **4 Revision History**

| Cł | hanges from Revision * (February 2017) to Revision A (September 2021) | Pag |
|----|---|-----|
| •  | 向 <i>特性</i> 部分添加了功能安全要点   |     |



# **Device Comparison Table**

## 表 5-1. TPL5x10Q Family of AEC-Q100 Nano- Power System Timers

| PART NUMBER  | SUPPLY CURRENT (Typ) | SPECIAL FEATURES         |
|--------------|----------------------|--------------------------|
|              |                      | Low Power Timer          |
| TPL5010-Q1   | 35 nA                | Watchdog Function        |
| TF 250 10-Q1 | 33 TIA               | Programmable Delay Range |
|              |                      | Manual Reset             |
|              |                      | Low Power Timer          |
|              |                      | MOS-Driver               |
| TPL5110-Q1   | 35 nA                | Programmable Delay Range |
|              |                      | Manual Reset             |
|              |                      | One-Shot Feature         |



# **5 Pin Configuration and Functions**

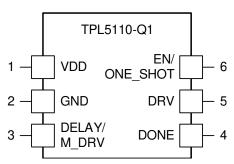


图 5-1. SOT-23 6-Lead DDC Top View

表 5-1. Pin Functions

|     | PIN             | TYPE <sup>(1)</sup> | DESCRIPTION  | APPLICATION INFORMATION  |  |  |
|-----|-----------------|---------------------|--|--|--|--|
| NO. |                 |                     | DESCRIPTION  | AFFEIGATION INFORMATION  |  |  |
| 1   | VDD             | Р                   | Supply voltage   |  |  |  |
| 2   | GND             | G                   | Ground   |  |  |  |
| 3   | DELAY/<br>M_DRV | I                   | Time interval set and manual MOSFET Power ON               | Resistance between this pin and GND is used to select the time interval. The manual MOSFET power ON switch is also connected to this pin.  |  |  |
| 4   | DONE            | I                   | Logic Input for watchdog functionality                     | Digital signal driven by the $\mu C$ to indicate successful processing.  |  |  |
| 5   | DRV             | 0                   | Power Gating output signal generated every t <sub>IP</sub> | The Gate of the MOSFET is connected to this pin. When DRV = LOW, the MOSFET is ON.   |  |  |
| 6   | EN/<br>ONE_SHOT | I                   | Selector of mode of operation                              | When EN/ONE_SHOT = HIGH, the TPL5110-Q1 works as a TIMER. When EN/ONE_SHOT = LOW, the TPL5110-Q1 turns on the MOSFET one time for the programmed time interval. The next power on of the MOSFET is enabled by the manual power ON. |  |  |

(1) G= Ground, P= Power, O= Output, I= Input.

Submit Document Feedback

## **6 Specifications**

## **6.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

|   | MIN  | MAX       | UNIT |
|---|------|-----------|------|
| Supply voltage (VDD-GND)                | -0.3 | 6.0       | V    |
| Input voltage at any pin <sup>(3)</sup> | -0.3 | VDD + 0.3 | V    |
| Input Current on any pin                | -5   | +5        | mA   |
| Storage temperature, T <sub>stg</sub>   | -65  | 150       | °C   |
| Junction temperature, TJ <sup>(2)</sup> |      | 150       | °C   |

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The maximum power dissipation is a function of T<sub>J</sub>(MAX), θ JA, and the ambient temperature, T<sub>A</sub>. The maximum allowable power dissipation at any ambient temperature is PDMAX = (T<sub>J</sub>(MAX) T<sub>A</sub>)/ θ JA. All numbers apply for packages soldered directly onto a PC hoard.
- (3) The voltage between any two pins should not exceed 6V.

### 6.2 ESD Ratings

|                    |                         |   | VALUE | UNIT |
|--------------------|-------------------------|---|-------|------|
| V                  | Electrostatic discharge | Human Body Model, per AEC Q100-002 <sup>(1)</sup> | ±2000 | V    |
| V <sub>(ESD)</sub> | Liectiostatic discharge | Charged-device model (CDM), per AEC Q100-011      | ±750  | "    |

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with ANSI/ESDA/JADEC JS-001 specification.

## 6.3 Recommended Operating Ratings

over operating free-air temperature range (unless otherwise noted)

|                          | MIN  | MAX | UNIT |
|--------------------------|------|-----|------|
| Supply Voltage (VDD-GND) | 1.8  | 5.5 | V    |
| Temperature Range        | - 40 | 125 | °C   |

### 6.4 Thermal Information

|                        |  | TPL5110-Q1 |      |
|------------------------|--|------------|------|
|                        | THERMAL METRIC <sup>(1)</sup>                | SOT-23     | UNIT |
|                        |  | 6 PINS     |      |
| R <sub>θ JA</sub>      | Junction-to-ambient thermal resistance       | 163        | °C/W |
| R <sub>θ JC(top)</sub> | Junction-to-case (top) thermal resistance    | 26         | °C/W |
| R <sub>θ JB</sub>      | Junction-to-board thermal resistance         | 57         | °C/W |
| ψJT                    | Junction-to-top characterization parameter   | 7.5        | °C/W |
| ψ ЈВ                   | Junction-to-board characterization parameter | 57         | °C/W |

 For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



#### 6.5 Electrical Characteristics

Specifications are for T<sub>A</sub>= 25°C, VDD-GND=2.5 V, unless otherwise stated. (1)

|                   | PARAMETER  | TEST CONI  | DITIONS           | MIN <sup>(2)</sup> | TYP <sup>(3)</sup>        | MAX <sup>(2)</sup> | UNIT   |
|-------------------|--|--|-------------------|--------------------|---------------------------|--------------------|--------|
| OWER SUF          | PLY  |  |                   |                    |                           |                    |        |
| IDD               | Supply current <sup>(4)</sup>                          | Operation mode                                   | Operation mode    |                    | 35                        | 50                 | nA     |
|                   |  | Digital conversion of external resistance (Rext) |                   |                    | 200                       | 400                | μA     |
| IMER              |  |  |                   |                    |                           |                    |        |
| t <sub>IP</sub>   | Time interval Period <sup>(5)</sup>                    | 1650 selectable Time                             | Min time interval |                    | 100                       |                    | ms     |
|                   |  | intervals  | Max time interval |                    | 7200                      |                    | S      |
|                   | Time interval Setting Accuracy <sup>(7)</sup>          | Excluding the precisio                           | n of Rext         |                    | ±0.6%                     |                    |        |
|                   | Time interval Setting Accuracy over supply voltage     | 1.8V ≤ VDD ≤ 5.5V                                |                   |                    | ±25                       |                    | ppm/V  |
| tosc              | Oscillator Accuracy                                    |  |                   | - 0.5%             |                           | 0.5%               |        |
|                   | Oscillator Accuracy over temperature <sup>(5)</sup>    | - 40°C ≤ T <sub>A</sub> ≤ 125°C                  |                   |                    | 150                       |                    | ppm/°0 |
|                   | Oscillator Accuracy over supply voltage <sup>(5)</sup> | 1.8V ≤ VDD ≤ 5.5V                                |                   |                    | ±0.4                      |                    | %/V    |
|                   | Oscillator Accuracy over life time <sup>(6)</sup>      |  |                   |                    | ±0.24%                    |                    |        |
| t <sub>DONE</sub> | Minimum DONE Pulse width (5)                           |  |                   |                    | 100                       |                    | ns     |
| t <sub>DRV</sub>  | DRV Pulse width  | DONE signal not rece                             | ived              |                    | t <sub>IP</sub> -<br>50ms |                    |        |
| t_Rext            | Time to convert Rext (5)                               |  |                   |                    | 100                       |                    | ms     |
| IGITAL LO         | GIC LEVELS   |  |                   |                    |                           |                    |        |
| VIH               | Minimum Logic High Threshold DONE pin                  |  |                   |                    | 0.7xVDD                   |                    | V      |
| VIL               | Maximum Logic Low Threshold DONE pin                   |  |                   |                    | 0.3xVDD                   |                    | V      |
| \/O.L.I           | La dia control High Land DDV air                       | lout = 100 μA                                    |                   | VDD - 0.3          |                           |                    | V      |
| VOH               | Logic output High Level DRV pin                        | lout = 1 mA                                      |                   | VDD - 0.7          |                           |                    | V      |
|                   |  | lout = - 100 μA                                  |                   |                    |                           | 0.3                | V      |
| VOL               | Logic output Low Level DRV pin                         | lout = -1 mA                                     |                   |                    |                           | 0.7                | V      |
| $VIH_{M\_DRV}$    | Minimum Logic High Threshold<br>DELAY/M_DRV pin (5)    |  |                   |                    | 1.5                       |                    | V      |

- (1) Electrical Characteristics Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that T<sub>J</sub> = T<sub>A</sub>. No specification of parametric performance is indicated in the electrical tables under conditions of internal self-heating where T<sub>J</sub> > T<sub>A</sub>. Absolute Maximum Ratings indicate junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.
- (2) Limits are specified by testing, design, or statistical analysis at 25°C. Limits over the operating temperature range are specified through correlations using statistical quality control (SQC) method.
- (3) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not specified on shipped production material.
- (4) The supply current excludes load and pull-up resistor current. Input pins are at GND or VDD.
- (5) This parameter is specified by design and/or characterization and is not tested in production.
- (6) Operational life time test procedure equivalent to 10 years.
- (7) The accuracy for time interval settings below 1second is ±100ms.

Submit Document Feedback

## 6.6 Timing Requirements

|                    |                                      |                          | MIN <sup>(3)</sup> NOM <sup>(4)</sup> MAX <sup>(3)</sup> | UNIT |
|--------------------|--------------------------------------|--------------------------|--|------|
| tr <sub>DRV</sub>  | Rise Time DRV <sup>(2)</sup>         | Capacitive load 50 pF    | 50   | ns   |
| tf <sub>DRV</sub>  | Fall Time DRV <sup>(2)</sup>         | Capacitive load 50 pF    | 50   | ns   |
| tD <sub>DONE</sub> | DONE to DRV delay                    | Min delay <sup>(1)</sup> | 100  | ns   |
|                    |                                      | Max delay (1)            | t <sub>DRV</sub>   |      |
| t <sub>M_DRV</sub> | Minimum Valid manual MOSFET Power ON | Observation time 30ms    | 20   | ms   |
| t <sub>DB</sub>    | De-bounce manual MOSFET Power ON     |                          | 20   | ms   |

- (1) from DRV falling edge.
- (2) This parameter is specified by design and/or characterization and is not tested in production.
- (3) Limits are specified by testing, design, or statistical analysis at 25°C. Limits over the operating temperature range are specified through correlations using statistical quality control (SQC) method.
- (4) Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not specified on shipped production material.

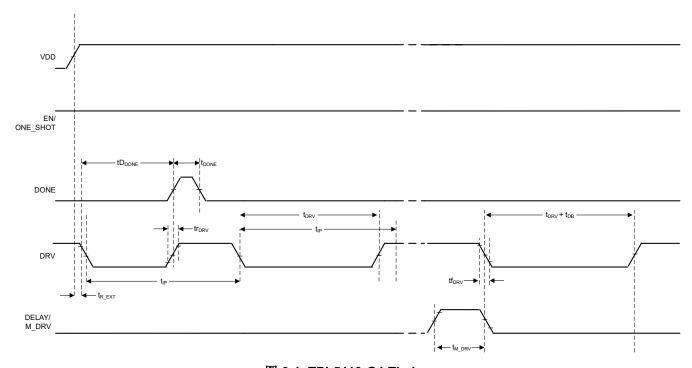
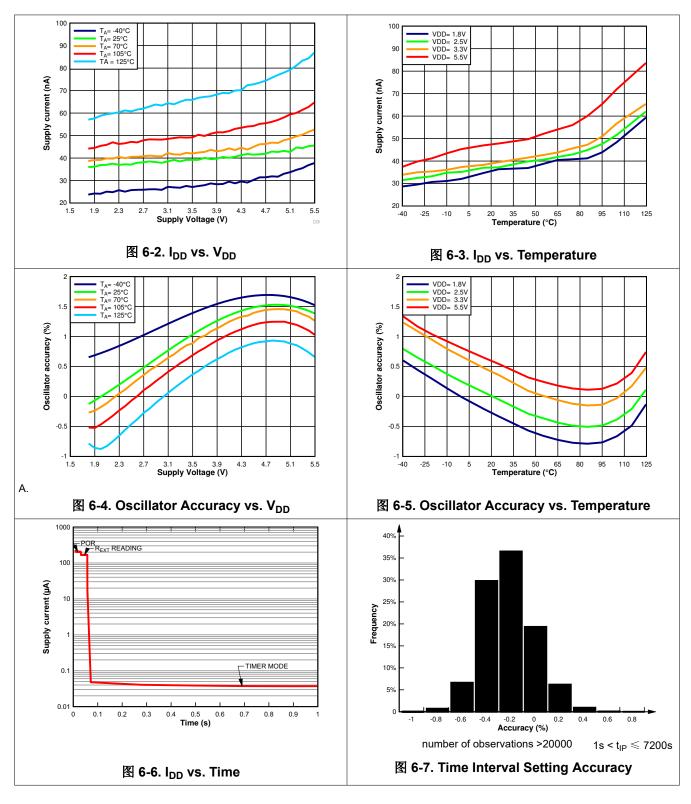


图 6-1. TPL5110-Q1 Timing



## **6.7 Typical Characteristics**



## 7 Detailed Description

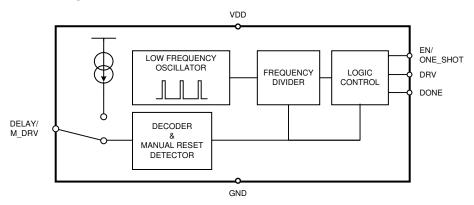
### 7.1 Overview

The TPL5110-Q1 is a timer with power gating feature. It is ideal for use in power-cycled applications and provides selectable timing from 100ms to 7200s.

Once configured in timer mode (EN/ONE\_SHOT= HIGH) the TPL5110-Q1 periodically sends out a DRV signal to a MOSFET to turn on the  $\mu$ C. If the  $\mu$ C replies with a DONE signal within the programmed time interval ( $t_{DRV}$ ) the TPL5110-Q1 turns off the  $\mu$ C, otherwise the TPL5110-Q1 keeps the  $\mu$ C in the on state for a time equal to  $t_{DRV}$ .

The TPL5110-Q1 can work also in a one-shot mode (EN/ONE\_SHOT= LOW). In this mode the DRV signal is sent out just one time at the power on of the TPL5110-Q1 to turn on the  $\mu$ C. If the  $\mu$ C replies with a DONE signal within the programmed time interval ( $t_{DRV}$ ) the TPL5110-Q1 turns off the  $\mu$ C, otherwise the TPL5110-Q1 keeps the  $\mu$ C in the on state for a time equal to  $t_{DRV}$ .

### 7.2 Functional Block Diagram



#### 7.3 Feature Description

The TPL5110-Q1 implements a periodical power gating feature or one shot power gating according to the EN/ ONE\_SHOT voltage. A manual MOSFET Power ON function is realized by momentarily pulling the DELAY/ M DRV pin to VDD.

#### 7.3.1 DRV

The gate of the MOSFET is connected to the DRV pin. When DRV= LOW, the MOSFET is turned ON. The pulse generated at DRV is equal to the selected time interval period, minus 50ms. It is shorter in the case of a DONE signal received from the  $\mu$ C. If the DONE signal is not received within the programmed time interval (minus 50ms), the DRV signal will be high for the last 50ms of the time interval in order to turn off the MOSFET before the next cycle starts.

The default value (after resistance reading) is HIGH. The signal is sent out from the TPL5110-Q1 when the programmed time interval starts. When the DRV is LOW, the manual power ON signal is ignored.

## **7.3.2 DONE**

The DONE pin is driven by a  $\mu$ C to signal that the  $\mu$ C is working properly. The TPL5110-Q1 recognizes a valid DONE signal as a low to high transition; if two or more DONE signals are received within the time interval, only the first DONE signal is processed. The minimum DONE signal pulse length is 100ns. When the TPL5110-Q1 receives the DONE signal it asserts DRV logic HIGH.

#### 7.4 Device Functional Modes

## 7.4.1 Start-Up

During start-up, after POR, the TPL5110-Q1 executes a one-time measurement of the resistance attached to the DELAY/M\_DRV pin in order to determine the desired time interval for DRV. This measurement interval is  $t_{R\_EXT}$ . During this measurement a constant current is temporarily flowing into  $R_{EXT}$ .

Copyright © 2021 Texas Instruments Incorporated

Submit Document Feedback

Once the reading of the external resistance is completed the TPL5110-Q1 enters automatically in one of the 2 modes according to the EN/ONE\_SHOT value. The EN/ONE\_SHOT pin must be hard wired to GND or VDD according to the required mode of operation.

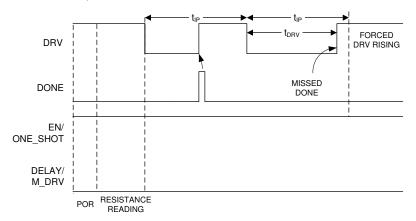


图 7-1. Start-Up - Timer Mode

#### 7.4.2 Timer Mode

During timer mode (EN/ONE\_SHOT = HIGH), the TPL5110-Q1 asserts periodic DRV pulses according to the programmed time interval. The length of the DRV pulses is set by the receiving of a DONE pulse from the uC. See  $\[ \]$  7-1.

#### 7.4.3 One-Shot Mode

During one-shot mode (EN/ONE\_SHOT = LOW), the TPL5110-Q1 generates just one pulse at the DRV pin which lasts according to the programmed time interval. In one-shot mode, other DRV pulses can be triggered using the DELAY/M\_DRV pin. If a valid manual power ON occurs when EN/ONE\_SHOT is LOW, the TPL5110-Q1 generates just one pulse at the DRV pin. The duration of the pulse is set by the programmed time interval. Also in this case, if a DONE signal is received within the programmed time interval (minus 50ms), the MOSFET connected to the DRV pin is turned off. See  $\cite{Most Normal Normal$ 

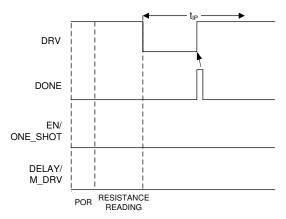


图 7-2. Start-Up One-Shot Mode, (DONE Received Within t<sub>IP</sub>)

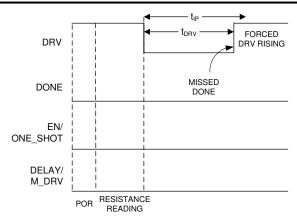


图 7-3. Start-Up One-Shot Mode, (No DONE Received Within t<sub>IP</sub>)

## 7.5 Programming

### 7.5.1 Configuring the Time Interval with the DELAY/M\_DRV Pin

The time interval between 2 adjacent DRV pulses (falling edges, in timer mode) is selectable through an external resistance ( $R_{EXT}$ ) between the DELAY/M\_DRV pin and ground. The resistance ( $R_{EXT}$ ) must be in the range between 500  $\Omega$  and 170k  $\Omega$ . At least a 1% precision resistance is recommended. See section #7.5.3 on how to set the time interval using  $R_{EXT}$ .

### 7.5.2 Manual MOSFET Power ON Applied to the DELAY/M\_DRV Pin

If VDD is connected to the DELAY/M\_DRV pin, the TPL5110-Q1 recognizes this as a manual MOSFET Power ON condition. In this case the time interval is not set. If the manual MOSFET Power ON is asserted during the POR or during the reading procedure, the reading procedure is aborted and is re-started as soon as the manual MOSFET Power ON switch is released. A pulse on the DELAY/M\_DRV pin is recognized as a valid manual MOSFET Power ON only if it lasts at least 20ms (observation time is 30ms). The manual MOSFET Power ON may be implemented using a switch (momentary mechanical action).

If the DRV is already LOW (MOSFET ON) the manual MOSFET Power ON is ignored.

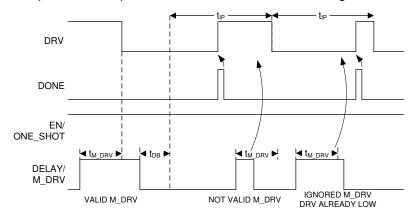


图 7-4. Manual MOSFET Power ON in Timer Mode



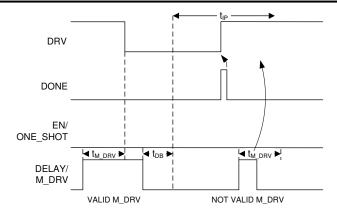


图 7-5. Manual MOSFET Power ON in One-Shot Mode

### 7.5.2.1 DELAY/M\_DRV

A resistance in the range between  $500\,\Omega$  and  $170k\,\Omega$  must to be connected to the DELAY/M\_DRV pin in order to select a valid time interval. At the POR and during the reading of the resistance, the DELAY/M\_DRV is connected to an analog signal chain through a mux. After the reading of the resistance, the analog circuit is switched off and the DELAY/M\_DRV is connected to a digital circuit.

In this state, a logic HIGH applied to the DELAY/M\_DRV pin is interpreted by the TPL5110-Q1 as a manual power ON. The manual power ON detection is provided with a de-bounce feature (on both edges) which makes the TPL5110-Q1 insensitive to the glitches on the DELAY/M DRV.

The M\_DRV must stay high for at least 20ms to be valid. Once a valid signal at DELAY/M\_DRV is understood as a manual power on, the DRV signal will be asserted in the next 10ms. Its duration will be according to the programmed time interval (minus 50ms), or less if the DONE is received.

A manual power ON signal resets all the counters. The counters will restart as soon as a valid manual power ON signal is recognized and the signal at DELAY/M\_DRV pin is asserted LOW. Due to the asynchronous nature of the manual power ON signal and its arbitrary duration, the LOW status of the DRV signal may be affected by an uncertainty of about ±5ms.

An extended assertion of a logic HIGH at the DELAY/M\_DRV pin will turn on the MOSFET for a time longer than the programmed time interval. DONE signals received while the DELAY/M\_DRV is HIGH are ignored. If the DRV is already LOW (MOSFET ON) the manual power ON is ignored.

#### 7.5.2.2 Circuitry

The manual Power ON may be implemented using a switch (momentary mechanical action). The TPL5110-Q1 offers 2 possible approaches according to the power consumption constraints of the application.

Product Folder Links: TPL5110-Q1



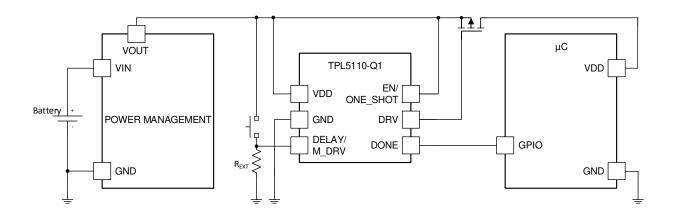


图 7-6. Manual MOSFET Power ON with SPST Switch

For use cases that do not require the lowest power consumption, using a single pole single throw switch may offer a lower cost solution. The DELAY/M\_DRV pin may be directly connected to VDD with R<sub>EXT</sub> in the circuit. The current drawn from the supply voltage during the manual power ON is given by VDD/R<sub>EXT</sub>.

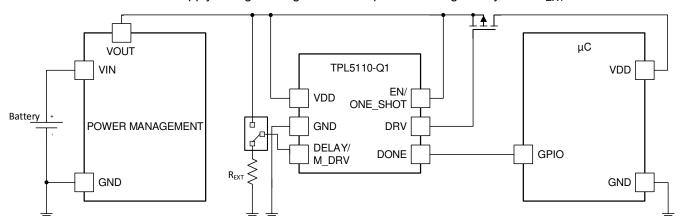


图 7-7. Manual MOSFET Power ON with SPDT Switch

The manual MOSFET Power ON function may also be asserted by switching DELAY/M\_DRV from R<sub>EXT</sub> to VDD using a single pole double throw switch, which will provide a lower power solution for the manual power ON, because no current flows.

#### 7.5.3 Selection of the External Resistance

In order to set the time interval, the external resistance R<sub>EXT</sub> is selected according the following formula:

$$R_{EXT} = 100 \left( \frac{-b + \sqrt{b^2 - 4a(c - 100 T)}}{2a} \right)$$
 (1)

### Where:

- · T is the desired time interval in seconds.
- R<sub>EXT</sub> is the resistance value to use in Ω.
- a,b,c are coefficients depending on the range of the time interval.

Copyright © 2021 Texas Instruments Incorporated

Submit Document Feedback



表 7-1. Coefficients for 方程式 1

| SET | Time Interval<br>Range (s)   | а       | b         | С          |
|-----|--|---------|-----------|------------|
| 1   | 1 <t≤ 5<="" td=""><td>0.2253</td><td>-20.7654</td><td>570.5679</td></t≤>       | 0.2253  | -20.7654  | 570.5679   |
| 2   | 5 <t≤ 10<="" td=""><td>-0.1284</td><td>46.9861</td><td>-2651.8889</td></t≤>    | -0.1284 | 46.9861   | -2651.8889 |
| 3   | 10 <t≤ 100<="" td=""><td>0.1972</td><td>-19.3450</td><td>692.1201</td></t≤>    | 0.1972  | -19.3450  | 692.1201   |
| 4   | 100 <t≤ 1000<="" td=""><td>0.2617</td><td>-56.2407</td><td>5957.7934</td></t≤> | 0.2617  | -56.2407  | 5957.7934  |
| 5   | T> 1000  | 0.3177  | -136.2571 | 34522.4680 |

### **EXAMPLE**

Required time interval: 8s

The coefficient set to be selected is the number 2. The formula becomes

$$R_{EXT} = 100 \left( \frac{46.9861 - \sqrt{46.9861^2 + 4*0.1284(-2561.8889 - 100*8)}}{2*0.1284} \right)$$
 (2)

The resistance value is 10.18 k $\Omega$ .

The following Look-Up-Tables contain example values of  $t_{\text{IP}}$  and their corresponding value of  $R_{\text{EXT}}$ .

#### 表 7-2. First 9 Time Intervals

| t <sub>IP</sub> (ms) | Resistance (Ω) | Closest real value ( $\Omega$ ) | Parallel of two 1% tolerance resistors, $(k \Omega)$ |
|----------------------|----------------|---------------------------------|--|
| 100                  | 500            | 500                             | 1.0 // 1.0   |
| 200                  | 1000           | 1000                            | -  |
| 300                  | 1500           | 1500                            | 2.43 // 3.92   |
| 400                  | 2000           | 2000                            | -  |
| 500                  | 2500           | 2500                            | 4.42 // 5.76   |
| 600                  | 3000           | 3000                            | 5.36 // 6.81   |
| 700                  | 3500           | 3500                            | 4.75 // 13.5   |
| 800                  | 4000           | 4000                            | 6.19 // 11.3   |
| 900                  | 4500           | 4501                            | 6.19 // 16.5   |

表 7-3. Most Common Time Intervals Between 1s to 2h

| t <sub>IP</sub> | Calculated Resistance (kΩ) | Closest Real Value (k Ω) | Parallel of Two 1% Tolerance Resistors, $(k\Omega)$ |
|-----------------|----------------------------|--------------------------|---|
| 1s              | 5.20                       | 5.202                    | 7.15 // 19.1  |
| 2s              | 6.79                       | 6.788                    | 12.4 // 15.0  |
| 3s              | 7.64                       | 7.628                    | 12.7// 19.1   |
| 4s              | 8.30                       | 8.306                    | 14.7 // 19.1  |
| 5s              | 8.85                       | 8.852                    | 16.5 // 19.1  |
| 6s              | 9.27                       | 9.223                    | 18.2 // 18.7  |
| 7s              | 9.71                       | 9.673                    | 19.1 // 19.6  |
| 8s              | 10.18                      | 10.180                   | 11.5 // 8.87  |
| 9s              | 10.68                      | 10.68                    | 17.8 // 26.7  |
| 10s             | 11.20                      | 11.199                   | 15.0 // 44.2  |
| 20s             | 14.41                      | 14.405                   | 16.9 // 97.6  |
| 30s             | 16.78                      | 16.778                   | 32.4 // 34.8  |
| 40s             | 18.75                      | 18.748                   | 22.6 // 110.0                                       |

Submit Document Feedback

Instruments www.ti.com.cn

| 表 7-3 Most Common      | <b>Time Intervals Between</b> | 1s to 2h  | (continued)                |
|------------------------|-------------------------------|-----------|----------------------------|
| 水 1-3. WOSt COIIIIIOII | Tillie lillervais Delweeli    | 15 (0 211 | (COIILIIIu <del>c</del> u) |

| t <sub>IP</sub> | Calculated Resistance (k Ω ) | Closest Real Value (k Ω) | Parallel of Two 1% Tolerance Resistors, (k $\Omega$ ) |
|-----------------|------------------------------|--------------------------|---|
| 50s             | 20.047                       | 20.047                   | 28.7 // 66.5  |
| 1min            | 22.02                        | 22.021                   | 40.2 // 48.7  |
| 2min            | 29.35                        | 29.349                   | 35.7 // 165.0   |
| 3min            | 34.73                        | 34.729                   | 63.4 // 76.8  |
| 4min            | 39.11                        | 39.097                   | 63.4 // 102.0   |
| 5min            | 42.90                        | 42.887                   | 54.9 // 196.0   |
| 6min            | 46.29                        | 46.301                   | 75.0 // 121.0   |
| 7min            | 49.38                        | 49.392                   | 97.6 // 100.0   |
| 8min            | 52.24                        | 52.224                   | 88.7 // 127.0   |
| 9min            | 54.92                        | 54.902                   | 86.6 // 150.0   |
| 10min           | 57.44                        | 57.437                   | 107.0 // 124.0  |
| 20min           | 77.57                        | 77.579                   | 140.0 // 174.0  |
| 30min           | 92.43                        | 92.233                   | 182.0 // 187.0  |
| 40min           | 104.67                       | 104.625                  | 130.0 // 536.00                                       |
| 50min           | 115.33                       | 115.331                  | 150.0 // 499.00                                       |
| 1h              | 124.91                       | 124.856                  | 221.0 // 287.00                                       |
| 1h30min         | 149.39                       | 149.398                  | 165.0 // 1580.0                                       |
| 2h              | 170.00                       | 170.00                   | 340.0 // 340.0  |

#### 7.5.4 Quantization Error

The TPL5110-Q1 can generate 1650 discrete timer intervals in the range of 100ms to 7200s. The first 9 intervals are multiples of 100ms. The remaining 1641 intervals cover the range between 1s to 7200s. Because they are discrete intervals, there is a quantization error associated with each value.

The quantization error can be evaluated according to the following formula:

$$Err = 100 \frac{\left(T_{DESIRED} - T_{ADC}\right)}{T_{DESIRED}} \tag{3}$$

Where:

$$T_{ADC} = INT \left[ \frac{1}{100} \left( a \frac{R_D^2}{100^2} + b \frac{R_D}{100} + c \right) \right]$$
 (4)

$$R_D = INT \left[ \frac{R_{EXT}}{100} \right] \tag{5}$$

R<sub>EXT</sub> is the resistance calculated with 方程式 1 and a,b,c are the coefficients of the equation listed in 表 7-1.

#### 7.5.5 Error Due to Real External Resistance

R<sub>EXT</sub> is a theoretical value and may not be available in standard commercial resistor values. It is possible to closely approach the theoretical R<sub>EXT</sub> using two or more standard values in parallel. However, standard values are characterized by a certain tolerance. This tolerance will affect the accuracy of the time interval.

The accuracy can be evaluated using the following procedure:

- 1. Evaluate the min and max values of R<sub>EXT</sub> (R<sub>EXT MIN</sub>, R<sub>EXT MAX</sub> with 方程式 1 using the selected commercial resistance values and their tolerances.
- 2. Evaluate the time intervals (T<sub>ADC MIN</sub>[R<sub>EXT MIN</sub>], T<sub>ADC MAX</sub>[R<sub>EXT MAX</sub>]) with 方程式 4.

3. Find the errors using 方程式 3 with  $T_{ADC\_MIN}$ ,  $T_{ADC\_MAX}$ .

The results of the formula indicate the accuracy of the time interval.

The example below illustrates the procedure.

- Desired time interval , T\_desired = 600s,
- Required R<sub>EXT</sub>, from 方程式 1, R<sub>EXT</sub>= 57.44k Ω.

From  $\frac{1}{8}$  7-3, R<sub>EXT</sub> can be built with a parallel combination of two commercial values with 1% tolerance: R1=107k  $\Omega$ , R2=124k  $\Omega$ . The uncertainty of the equivalent parallel resistance can be found using:

$$uR_{\parallel} = R_{\parallel} \sqrt{\left(\frac{u_{R1}}{R1}\right)^2 + \left(\frac{u_{R2}}{R2}\right)^2}$$
 (6)

Where uRn (n=1,2) represent the uncertainty of a resistance,

$$u_{Rn} = Rn \frac{Tolerance}{\sqrt{3}} \tag{7}$$

The uncertainty of the parallel resistance is 0.82%, meaning the value of  $R_{EXT}$  may range between  $R_{EXT\_MIN}$  = 56.96 k $\Omega$  and  $R_{EXT\_MAX}$  = 57.90 k $\Omega$ .

Using these value of  $R_{EXT}$ , the digitized timer intervals calculated with 方程式 4 are respectively  $T_{ADC\_MIN}$  = 586.85 s and  $T_{ADC\_MAX}$  = 611.3 s, giving an error range of -1.88% / +2.19%. The asymmetry of the error range is due to the quadratic transfer function of the resistance digitizer.

Submit Document Feedback

## 8 Application and Implementation

#### Note

以下应用部分中的信息不属于 TI 器件规格的范围, TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计,以确保系统功能。

### 8.1 Application Information

In battery powered applications one design constraint is the need for low current consumption. The TPL5110-Q1 is suitable in applications where there is a need to monitor environmental conditions at a fixed time interval. Often in these applications a watchdog or other internal timer in a  $\mu$ C is used to implement a wakeup function. Typically, the power consumption of these functions is not optimized. Using the TPL5110-Q1 to implement a periodical power gating of the  $\mu$ C or of the entire system the current consumption will be only tens of nA.

### 8.2 Typical Application

The TPL5110-Q1 can be used in environment sensor nodes such as humidity and temperature sensor node. The sensor node has to measure the humidity and the temperature and transmit the data through a low power RF micro such as the CC2531. Since the temperature and the humidity in home application do not change so fast, the measurement and the transmission of the data can be done at very low rate, such as every 30 seconds. The RF micro should spend most of the time in counting the elapsed time, but using the TPL5110-Q1 it is possible to complete turn off the RF micro and extend the battery life. The TPL5110-Q1 will turn on the RF micro when the programmed time interval elapses or for debug purpose with the manual MOSFET Power ON switch.

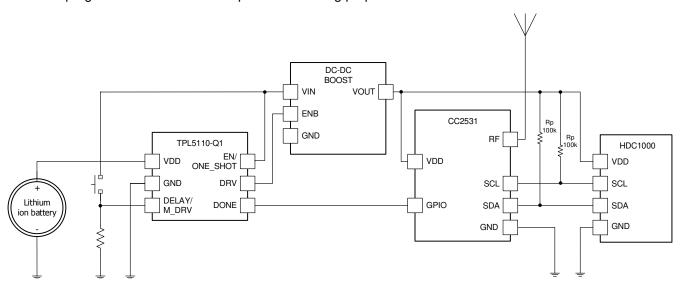


图 8-1. Sensor Node

#### 8.2.1 Design Requirements

The Design is driven by the low current consumption constraint. The data are usually acquired on a rate which is in the range between 30s and 60s. The highest necessity is the maximization of the battery life. The TPL5110-Q1 helps achieve this goal because it allows turning off the RF micro.

#### 8.2.2 Detailed Design Procedure

When the focal constraint is the battery life, the selection of a low power voltage regulator and low leakage MOSFET to power gate the  $\mu$ C is mandatory. The first step in the design is the calculation of the power consumption of each device in the different mode of operations. An example is the HDC1000, in measurement mode the RF micro is in normal operation and transmission. The different modes offer the possibility to select the appropriate time interval which respect the application constraint and maximize the life of the battery.



### 8.2.3 Application Curve

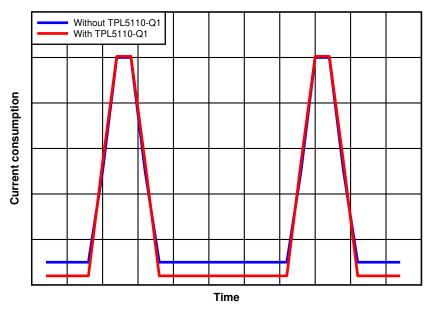


图 8-2. Effect of TPL5110-Q1 on Current Consumption

# 9 Power Supply Recommendations

The TPL5110-Q1 requires a voltage supply within 1.8 V and 5.5 V. A multilayer ceramic bypass X7R capacitor of 0.1  $\mu$  F between VDD and GND pin is recommended.

Submit Document Feedback

### 10 Layout

## 10.1 Layout Guidelines

The DELAY/M\_DRV pin is sensitive to parasitic capacitance. It is suggested that the traces connecting the resistance on this pin to GROUND be kept as short as possible to minimize parasitic capacitance. This capacitance can affect the initial set up of the time interval. Signal integrity on the DRV pin is also improved by keeping the trace length between the TPL5110-Q1 and the gate of the MOSFET short to reduce the parasitic capacitance. The EN/ONE\_SHOT needs to be tied to GND or VDD with short traces.

## 10.2 Layout Example

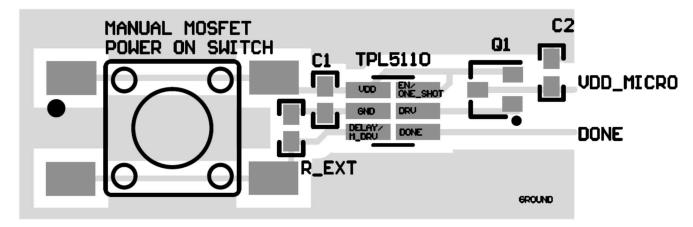


图 10-1. Layout



## 11 Device and Documentation Support

## 11.1 接收文档更新通知

要接收文档更新通知,请导航至 ti.com 上的器件产品文件夹。点击 订阅更新 进行注册,即可每周接收产品信息更改摘要。有关更改的详细信息,请查看任何已修订文档中包含的修订历史记录。

### 11.2 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料,可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范,并且不一定反映 TI 的观点;请参阅 TI 的《使用条款》。

#### 11.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

所有商标均为其各自所有者的财产。

### 11.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 11.5 术语表

TI术语表本术语表列出并解释了术语、首字母缩略词和定义。

Submit Document Feedback



## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Copyright © 2021 Texas Instruments Incorporated

Submit Document Feedback

## 重要声明和免责声明

TI 提供技术和可靠性数据(包括数据表)、设计资源(包括参考设计)、应用或其他设计建议、网络工具、安全信息和其他资源,不保证没有瑕疵且不做出任何明示或暗示的担保,包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任:(1) 针对您的应用选择合适的 TI 产品,(2) 设计、验证并测试您的应用,(3) 确保您的应用满足相应标准以及任何其他安全、安保或其他要求。这些资源如有变更,恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的应用。严禁对这些资源进行其他复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务,TI 对此概不负责。

TI 提供的产品受 TI 的销售条款 (https://www.ti.com/legal/termsofsale.html) 或 ti.com 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

邮寄地址:Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2021,德州仪器 (TI) 公司 www.ti.com 10-May-2021

#### **PACKAGING INFORMATION**

| Orderable Device | Status (1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan     | Lead finish/<br>Ball material | MSL Peak Temp      | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|------------------|------------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|-------------------------|---------|
| TPL5110QDDCRQ1   | ACTIVE     | SOT-23-THIN  | DDC                | 6    | 3000           | RoHS & Green | SN                            | Level-1-260C-UNLIM | -40 to 125   | 13ZX                    | Samples |
| TPL5110QDDCTQ1   | ACTIVE     | SOT-23-THIN  | DDC                | 6    | 250            | RoHS & Green | SN                            | Level-1-260C-UNLIM | -40 to 125   | 13ZX                    | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# **PACKAGE OPTION ADDENDUM**

www.ti.com 10-May-2021

#### OTHER QUALIFIED VERSIONS OF TPL5110-Q1:

• Catalog : TPL5110

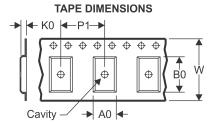
NOTE: Qualified Version Definitions:

• Catalog - TI's standard catalog product

www.ti.com 29-Oct-2021

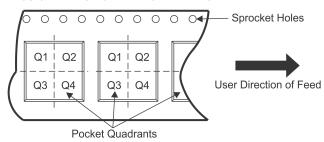
## TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width     |
|----|---|
|    | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

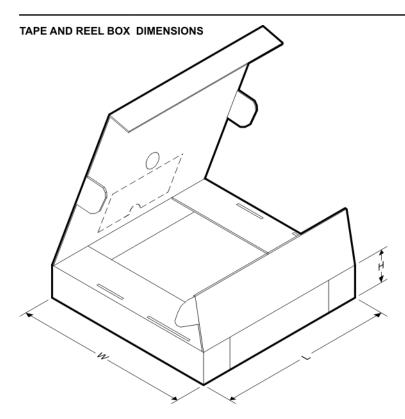
### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device         | Package<br>Type | Package<br>Drawing |   | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|----------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TPL5110QDDCRQ1 | SOT-<br>23-THIN | DDC                | 6 | 3000 | 178.0                    | 8.4                      | 3.2        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |
| TPL5110QDDCTQ1 | SOT-<br>23-THIN | DDC                | 6 | 250  | 178.0                    | 8.4                      | 3.2        | 3.2        | 1.4        | 4.0        | 8.0       | Q3               |

www.ti.com 29-Oct-2021

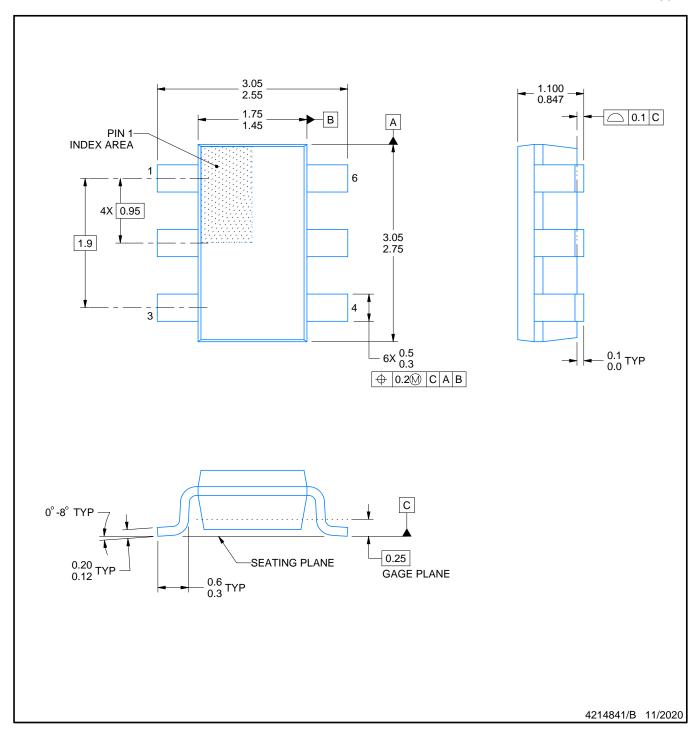


#### \*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPL5110QDDCRQ1 | SOT-23-THIN  | DDC             | 6    | 3000 | 208.0       | 191.0      | 35.0        |
| TPL5110QDDCTQ1 | SOT-23-THIN  | DDC             | 6    | 250  | 208.0       | 191.0      | 35.0        |



SOT

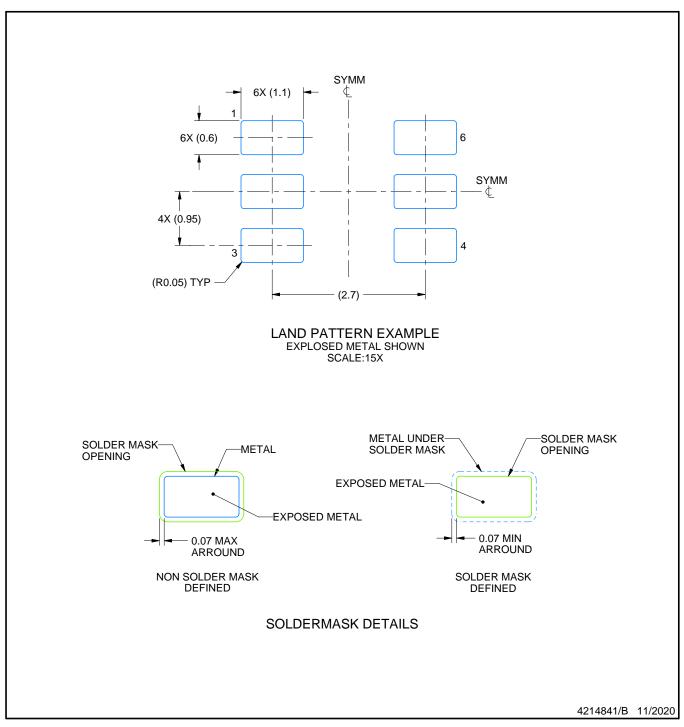


### NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.
   Reference JEDEC MO-193.



SOT

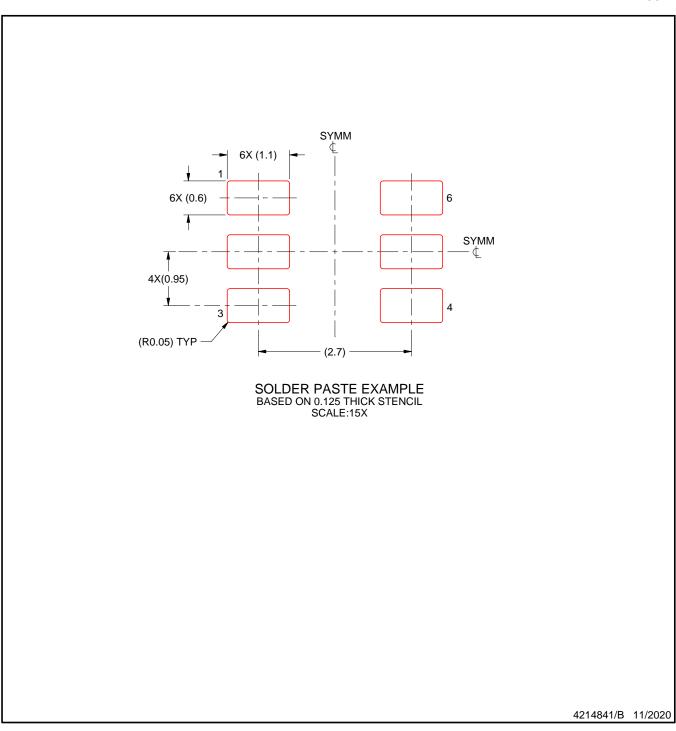


NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOT



NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

  7. Board assembly site may have different recommendations for stencil design.



## 重要声明和免责声明

TI"按原样"提供技术和可靠性数据(包括数据表)、设计资源(包括参考设计)、应用或其他设计建议、网络工具、安全信息和其他资源,不保证没有瑕疵且不做出任何明示或暗示的担保,包括但不限于对适销性、某特定用途方面的适用性或不侵犯任何第三方知识产权的暗示担保。

这些资源可供使用 TI 产品进行设计的熟练开发人员使用。您将自行承担以下全部责任:(1) 针对您的应用选择合适的 TI 产品,(2) 设计、验证并测试您的应用,(3) 确保您的应用满足相应标准以及任何其他功能安全、信息安全、监管或其他要求。

这些资源如有变更,恕不另行通知。TI 授权您仅可将这些资源用于研发本资源所述的 TI 产品的应用。严禁对这些资源进行其他复制或展示。您无权使用任何其他 TI 知识产权或任何第三方知识产权。您应全额赔偿因在这些资源的使用中对 TI 及其代表造成的任何索赔、损害、成本、损失和债务,TI 对此概不负责。

TI 提供的产品受 TI 的销售条款或 ti.com 上其他适用条款/TI 产品随附的其他适用条款的约束。TI 提供这些资源并不会扩展或以其他方式更改 TI 针对 TI 产品发布的适用的担保或担保免责声明。

TI 反对并拒绝您可能提出的任何其他或不同的条款。

邮寄地址:Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2021,德州仪器 (TI) 公司